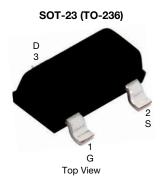


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Vishay Siliconix

N-Channel 20 V (D-S) MOSFET



Marking code: N2

PRODUCT SUMMARY						
V _{DS} (V)	20					
$R_{DS(on)}$ max. (Ω) at $V_{GS} = 4.5 \text{ V}$	0.057					
$R_{DS(on)}$ max. (Ω) at $V_{GS} = 2.5 \text{ V}$	0.075					
Q _g typ. (nC)	3.5					
I _D (A)	2.9					
Configuration	Single					

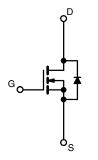
FEATURES

- TrenchFET® power MOSFET
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



APPLICATIONS

- Load switching for portable devices
- DC/DC converter



N-Channel MOSFET

ORDERING INFORMATION				
Package	SOT-23			
Lead (Pb)-free	Si2302CDS-T1-E3			
Lead (Pb)-free and halogen-free	Si2302CDS-T1-GE3			

ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C, unless otherwise noted)						
PARAMETER		SYMBOL	5 S	STEADY STATE	UNIT	
Drain-source voltage		V_{DS}	20	20	V	
Gate-source voltage		V_{GS}	± 8	± 8		
Continuous drain current (T _J = 150 °C) ^a	T _A = 25 °C	I _D	2.9	2.6	А	
	T _A = 70 °C		2.3	2.1		
Pulsed drain current b		I _{DM}	10	10	A	
Continuous source current (diode conduction) a		I _S	0.72	0.6		
Power dissipation ^a	T _A = 25 °C	P _D	0.86	0.71	W	
	T _A = 70 °C		0.55	0.46		
Operating junction and storage temperature range		T _J , T _{sta}	-55 to +150	-55 to +150	°C	

THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	TYPICAL	MAXIMUM	UNIT
Maximum junction-to-ambient ^a	t ≤ 5 s	R _{thJA}	120	145	°C/W
	Steady state		140	175	
Maximum junction-to-foot	Steady state	R _{thJF}	62	78	

Notes

- a. Surface mounted on 1" x 1" FR4 board
- b. Pulse width limited by maximum junction temperature

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SPECIFICATIONS (T _A = 25 °C, unless otherwise noted)							
			LIMITS				
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT	
Static	Static						
Drain-source breakdown voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	20	-	-	V	
Gate-threshold voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu A$	0.40	-	0.85	ľ	
Gate-body leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 8 \text{ V}$	-	-	± 100	nA	
		V _{DS} = 20 V, V _{GS} = 0 V	-	-	0.1		
Zero gate voltage drain current	I _{DSS}	V _{DS} = 20 V, V _{GS} = 0 V, T _J = 50 °C	=.	-	4	μΑ	
		V _{DS} = 20 V, V _{GS} = 0 V, T _J = 70 °C	-	-	15		
On-state drain current a	I _{D(on)}	$V_{DS} \ge 10 \text{ V}, V_{GS} = 4.5 \text{ V}$	6	-	-	Α	
B :		$V_{GS} = 4.5 \text{ V}, I_D = 3.6 \text{ A}$	-	0.045	0.057	Ω	
Drain-source on-resistance a	R _{DS(on)}	$V_{GS} = 2.5 \text{ V}, I_D = 3.1 \text{ A}$	-	0.056	0.075		
Forward transconductance a	9 _{fs}	V _{DS} = 5 V, I _D = 3.6 A	-	13	-	S	
Diode forward voltage	V _{SD}	I _S = 0.95 A, V _{GS} = 0 V	=.	0.7	1.2	V	
Dynamic ^b							
Total gate charge	Qg			3.5	5.5		
Gate-source charge	Q _{gs}	$V_{DS} = 10 \text{ V}, V_{GS} = 4.5 \text{ V}, I_D = 3.6 \text{ A}$	=.	0.6	-	nC	
Gate-drain charge	Q _{gd}		-	0.45	-	1	
Gate resistance	Rg	f = 1 MHz	2	4	8	Ω	
Switching							
Turn-on delay time	t _{d(on)}		-	8	15		
Rise time	t _r	$V_{DD} = 10 \text{ V}, R_1 = 2.78 \Omega$	-	7	15		
Turn-off delay time	t _{d(off)}	$I_D \cong 3.6 \text{ A}, V_{GEN} = 4.5 \text{ V}, R_g = 1 \Omega$	-	30	45	ns	
Fall time	t _f		-	7	15		
Source-drain reverse recovery time	t _{rr}	1 0 C A 4:/4+ 100 A / -	-	8.5	15		
Body diode reverse recovery charge	Q _{rr}	I _F = 3.6 A, di/dt = 100 A/μs	-	2	4	nC	

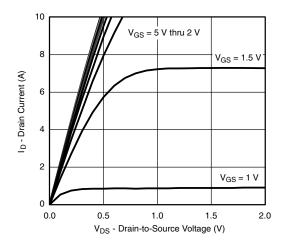
Notes

- a. Pulse test: Pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%$
- b. Guaranteed by design, not subject to production testing

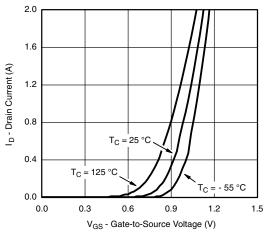
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



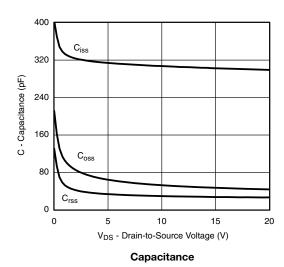
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

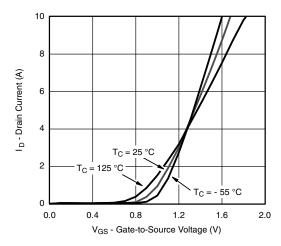


Output Characteristics

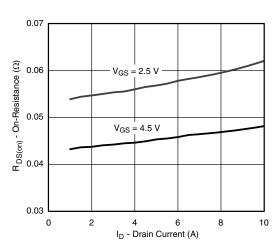


Transfer Characteristics

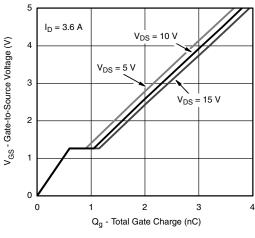




Transfer Characteristics

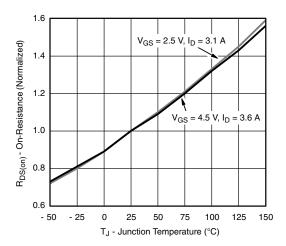


On-Resistance vs. Drain Current

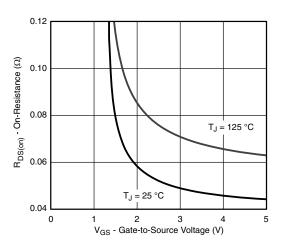




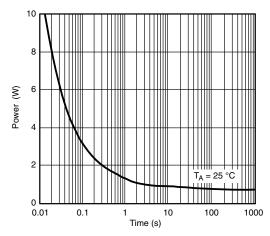
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



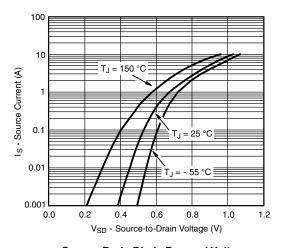
On-Resistance vs. Junction Temperature



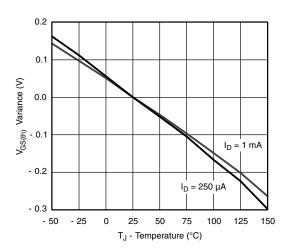
On-Resistance vs. Gate-to-Source Voltage



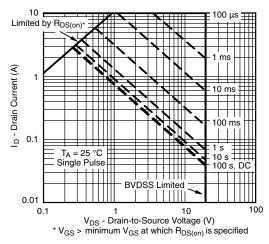
Single Pulse Power



Source-Drain Diode Forward Voltage



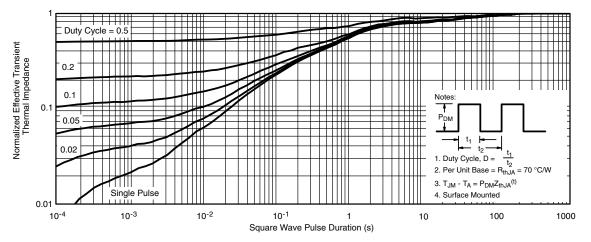
Threshold Voltage



Safe Operating Area, Junction-to-Ambient



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



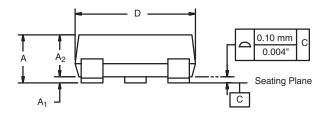
Normalized Thermal Transient Impedance, Junction-to-Ambient

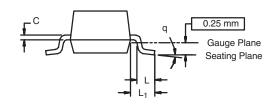
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SOT-23 (TO-236): 3-LEAD







Dim	MILLIN	IETERS	INCHES		
	Min	Max	Min	Max	
Α	0.89	1.12	0.035	0.044	
A ₁	0.01	0.10	0.0004	0.004	
A ₂	0.88	1.02	0.0346	0.040	
b	0.35	0.50	0.014	0.020	
С	0.085	0.18	0.003	0.007	
D	2.80	3.04	0.110	0.120	
E	2.10	2.64	0.083	0.104	
E ₁	1.20	1.40	0.047	0.055	
е	0.95 BSC		0.0374 Ref		
e ₁	1.90 BSC		0.0748 Ref		
L	0.40	0.60	0.016	0.024	
L ₁	0.64 Ref		0.025 Ref		
S	0.50 Ref		0.020 Ref		
q	3°	8°	3°	8°	
ECN: S-03946-Rev. K. 09-	Jul-01				

DWG: 5479

Document Number: 71196 www.vishay.com



RECOMMENDED MINIMUM PADS FOR SOT-23



Recommended Minimum Pads Dimensions in Inches/(mm)

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APPLICATION NOTE

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